

TRIAC BT138S

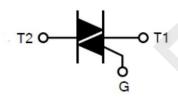
#### **FEATURES**

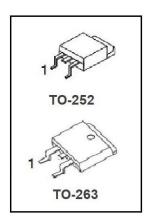
This device of sensitive TRIAC product is a glass passivated device, has a low gate trigger current, high stability in gate trigger current to variation of operating temperature and high off state voltage.

### **APPLICATIONS**

This device is suitable for low power AC switching application, phase control application such as fan speed and temperature modulation control, lighting control and static switching relay.

#### SYMBOL:





| Package | Pin assignment |    |   |  |  |
|---------|----------------|----|---|--|--|
|         | 1              | 2  | 3 |  |  |
| TO-252  | T1             | T2 | G |  |  |
| TO-263  | T1             | T2 | G |  |  |

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## **ABSOLUTE MAXIMUM RATINGS**

| PARAMETER                            | SYMBOL                              | VALUE                 |            |     | UNIT             |
|--------------------------------------|-------------------------------------|-----------------------|------------|-----|------------------|
| Repetitive Peak Off-State Voltages   | V <sub>DRM</sub> , V <sub>RRM</sub> | BT138S-600(D/E/F) 600 |            | V   |                  |
|                                      |                                     | BT138S-8              | 300(D/E/F) | 800 | V                |
| RMS on-State Current                 | I <sub>T(RMS)</sub>                 | 12                    |            |     | Α                |
| Non-Repetitive Peak On-State Current | I <sub>TSM</sub>                    | 120                   |            |     | A                |
| I <sup>2</sup> t for fusing          | l <sup>2</sup> t                    | 78                    |            |     | A <sup>2</sup> s |
| Repetitive rate of rise of on-state  |                                     |                       |            |     |                  |
| current                              | dIT/dt                              | I-IV 50               |            |     | A/uS             |
| after triggering                     |                                     |                       |            |     |                  |
| Peak gate current                    | $I_{GM}$                            | 4                     |            |     | Α                |
| Peak Gate Power                      | $P_GM$                              | 5                     |            |     | W                |
| Average Gate Power                   | $P_{G(AV)}$                         | 1                     |            |     | W                |
| Operating junction temperature       | TJ                                  | -40~+125              |            |     | ${\mathbb C}$    |
| Storage Temperature                  | T <sub>STG</sub>                    | -40 ~ +150            |            |     | ${\mathbb C}$    |



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# **ELECTRICAL CHARACTERISTICS** (TJ=25°C)

| Parameter                                  | Symbol Test Conditions |  | MIN    | MAX |     | Units |    |      |
|--|------------------------|--|--------|-----|-----|-------|----|------|
| Parameter Symbol Test Conditions           |                        | 115  | IVIIIN | D   | Е   | F     |    |      |
| Peak Repetitive Forward or                 | $I_{DRM}$              | V <sub>AK</sub> = Rated V <sub>DRM</sub> or                              |        |     | 5   |       | uA |      |
| Reverse Blocking Current                   | $I_{RRM}$              | V <sub>RRM</sub> ;   | 1      |     | 3   |       | uA |      |
| Gate Trigger Current                       | l <sub>GT</sub>        | $V_D$ =12V,<br>$R_L$ =100 $\Omega$                                       | - 1    |     | 5   | 10    | 25 | - mA |
|  |                        |  | II     |     | 5   | 10    | 25 |      |
|  |                        |  | III    |     | 5   | 10    | 25 |      |
|  |                        |  | IV     |     | 10  | 25    | 50 |      |
| Gate Trigger Voltage                       | V <sub>GT</sub>        | V <sub>D</sub> =12V, R <sub>L</sub> =100Ω                                |        |     | 1.3 |       | V  |      |
| Gate Non-Trigger Voltage                   | $V_{GD}$               | $V_D = V_{DRM}, R_L = 33 \text{ k}\Omega,$ $T_j = 125 \text{ °C}$        |        | 0.2 |     |       | V  |      |
| Peak Forward On-State<br>Voltage           | V <sub>TM</sub>        | IT=15A,  |        |     | 1.6 |       | V  |      |
| Latch Current I∟                           |                        | I <sub>L</sub> I <sub>G</sub> =1.2I <sub>G</sub> T                       | I      |     | 10  | 20    | 40 |      |
|  | ,                      |  | II     |     | 20  | 40    | 80 | 4    |
|  | IL                     |  | III    |     | 10  | 20    | 40 | - mA |
|  |                        |  | IV     |     | 10  | 20    | 40 |      |
| Holding Current                            | lμ                     | IT=0.1A  |        |     | 10  | 15    | 35 | mA   |
| Critical Rate of Rise of Off-State Voltage | dV/dt                  | V <sub>D</sub> =67%V <sub>DRM</sub> , T <sub>J</sub> =25°C,<br>Gate open |        | 40  |     |       |    | V/µs |

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